Claims

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- 1. Method for etching a substrate, comprising placing said substrate in an etching chamber, introducing a first etchant and/or etch catalyst originating from a first source into 5 said etching chamber, introducing a second etchant and/or etch catalyst originating from a second source, flushing said etching chamber following etching and removing said substrate, wherein the first etchant and/or etch catalyst is fed to the etching chamber from the first source through an auxiliary chamber, characterised in that the second etchant and/or etch catalyst is supplied through another path to said etching chamber and in that passing off said 10 first etchant and/or etch catalyst through the auxiliary chamber is realised intermittently such that there is never a direct connection between the etching chamber and said first source.
 - 2. Method according to Claim 1 wherein, after treatment of said substrate, flushing of said etching chamber is carried out via said auxiliary chamber.
- 3. Method according to one of the preceding claims, wherein the feed of said other 15 reactant and/or other catalyst to said chamber is shut off when said auxiliary chamber is connected to said etching chamber.
 - 4. Method according to one of the preceding claims, wherein the first reactant is HF.
- 5. Installation for etching a substrate (32), comprising an etching chamber (1) provided with an entry/exit opening (30) for said substrate, an inlet/discharge opening (2) for reactants and/or catalyst connected to a piping system for the separate supply of at least two reactants and/or catalysts, one feed comprising an auxiliary chamber (17) provided with an inlet and outlet each having a controller regulated shut-off valve (15, 16), the outlet being connected to the etching chamber and the inlet to the reactant and/or catalyst feed, characterised in that said controller is realised such that only one of said valves (15, 16) can be opened.
 - 6. Installation according to Claim 5, wherein a bypass line (18) for said auxiliary chamber is present.
- 7. Installation according to Claim 5 or 6, wherein said etching chamber is connected 30 to a vacuum pump (12).

- 9. Installation according to one of Claims 5 8, wherein said etching chamber comprises a construction which takes the vacuum in said etching chamber and is made exclusively of plastic.
- 10. Installation according to Claim 9, wherein said plastic construction comprises 5 polyvinylidene fluoride.
